NSN 5961-01-249-2656

Demilitarization: Yes - demil/mli

Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-249-2656 **Inclosure Material:** Metal **Overall Length:** Between 10.751 inches and 11.323 inches **Function For Which Designed:** Rectifier **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Burn in **Overall Width Across Flats:** Between 1.631 inches and 1.750 inches **Thread Size:** 0.750 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 1000.0 repetitive peak reverse voltage and 1000.0 repetitive peak off-state voltage and 20.0 peak gate voltage **Current Rating Per Characteristic:** 350.00 amperes forward current, total rms universal and 4.00 amperes repetitive peak forward current torr and 10000.00 amperes peak forward surge current nanoamperes **Power Rating Per Characteristic:** 16.0 watts small-signal input power, common-collector blank and 3.0 watts small-signal input power, common-collector universal **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 insulated wire lead w/terminal lug and 1 threaded stud and 1 uninsulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure:**